Electron cyclotron mass in undoped CdTe/CdMnTe quantum wells

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Optically detected cyclotron resonance of two-dimensional electrons has been studied in nominally undoped CdTe/(Cd,Mn)Te quantum wells. The enhancement of carrier quantum confinement results in an increase of the electron cyclotron mass from $0.099m_0$ to $0.112m_0$ with well width decreasing from 30 down to 3.6 nm. Model calculations of the electron effective mass have been performed for this material system and good agreement with experimental data is achieved for an electron-phonon coupling constant $\alpha=0.32$.

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I. INTRODUCTION

The effective masses of carriers (electrons and holes) are among the basic parameters for semiconductors and semiconductor heterostructures. Nowadays exhaustive information is available for heterostructures based on III-V semiconductors, e.g. GaAs/(Al,Ga)As heterosystems. However, only limited experimental data have been reported so far for the II-VI family of semiconductor heterostructures. Among them are the structures based on CdTe, which are rather popular for optical studies. One of the attractions to this material is the possibility to introduce magnetic Mn-ions in the cation sublattice. The strong exchange interaction of free carriers with localized spins of magnetic ions gives rise to giant magneto-optical effects, e.g. the giant Zeeman splitting of the band states, giant Faraday rotation, etc. [1]. (Cd,Mn)Te, (Cd,Mg)Te and (Cd.Zn)Te are among the barrier materials to confine carriers in CdTe quantum wells. In this paper we study experimentally the dependence of the electron effective mass on quantum well (QW) width for CdTe/(Cd,Mn)Te heterostructures.

The cyclotron resonance (CR) technique is widely used for evaluation of the fundamental parameters of heterostructures, including the carriers effective masses. It has been recently applied to modulation-doped CdTe/(Cd,Mg)Te QWs and the electron effective mass has been measured for these QWs with widths varied between 7.5 and 30 nm $\left[2,\,3\right]$ each, with a 2D electron gas density of 4×10^{11} cm⁻². One of the impediments for the conventional cyclotron resonance technique is that the carrier density has to be large enough to produce a noticeable change in the absorption of microwave or farinfrared (FIR) radiation. This limitation does not allow to measure carrier effective masses in undoped systems. It has been overcome by invention of the Optically Detected of Cyclotron Resonance (ODCR, or ODR) technique (see [4] and references therein).

The ODR technique is based on variation of the optical properties, such as the photoluminescence intensity under absorption of microwave or FIR radiation by free carriers. It was proved to be extremely sensitive and has been successfully used to measure the effective masses of electrons and holes in bulk GaAs, InP, CdTe [5, 6, 7], and SiC [8]. It was also developed to study 2D electron states in GaAs/(Al,Ga)As heterostructures [9, 10, 11] and internal transitions of neutral and charged magnetoexcitons [12, 13, 14]. Another advantage of the ODR technique is related to its spectral selectivity, which allows for selecting the signal from different quantum wells grown in the same structure by analyzing the corresponding photoluminescence emission lines. Therefore, the ODR technique is very well suited for measurements of the electron effective masses in undoped CdTe-based QWs of different widths.

II. EXPERIMENT

We have studied a CdTe/Cd_{0.86}Mn_{0.14}Te quantum heterostructure grown by molecular beam epitaxy on an (100)-oriented CdTe substrate. The structure contains four consequently grown CdTe wells with width $L_Z = 30, 9, 3.6$ and 1.2 nm separated by 50-nm-thick Cd_{0.86}Mn_{0.14}Te barriers from each other. Typical photoluminescence (PL) and reflectivity spectra of such structures can be found in [15, 16, 17].

Experiments were carried out at a temperature of T = 4.2 K in a He exchange cryostat in magnetic fields up to B = 8.3 T. The sample was mounted on a rotating platform, which enables ODR measurements in tilted magnetic fields in order to check the two-dimensional character of the studied resonances. Most experimental data were collected in magnetic fields oriented parallel to the structure growth axis ($\theta = 0^{\circ}$) with the cyclotron motion of electrons in the plane of the quantum wells. Photoexcitation of the samples by a HeNe laser and collection of the luminescence signal was provided via optical fibers. The spot of the HeNe laser beam ($\lambda = 6328$ Å, power up to 20 mW) was overlapped by the spot of a CO₂ pumped

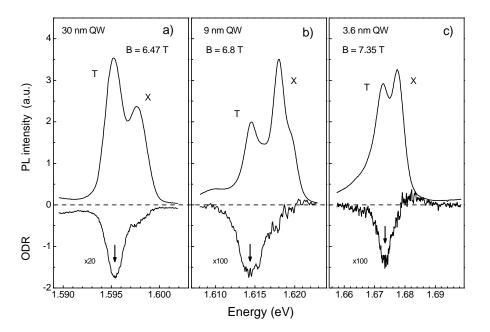


FIG. 1: Photoluminescence and ODR signal spectra measured for $CdTe/Cd_{0.86}Mn_{0.14}Te$ QWs with widths equal to: (a) 30 nm, (b) 9 nm, and (c) 3.6 nm. Spectra are measured at magnetic fields for which the FIR radiation induces the maximal changes, i.e. under conditions of cyclotron resonance for electrons. T=4.2K. The photon energies corresponding to the maximum of the ODR signal are marked with arrows. Note that the magnetic fields scans of the cyclotron resonances shown in Fig. 3 were detected at these energies.

FIR laser. Far infrared (FIR) radiation ($\lambda_{FIR} = 163 \ \mu \text{m}$, $E_{FIR} = 7.6 \text{ meV}$) with a power up to 15 mW was guided into the cryostat via a stainless steel pipe and focused on the sample by a Teflon lens. Photoluminescence (PL) signal was analyzed with a 0.6 m grating spectrometer equipped with a cooled photomultiplier.

The FIR laser beam was mechanically chopped. The influence of the FIR radiation on the PL spectra was synchronously detected by a lock-in amplifier at various magnetic fields. The ODR signal was normalized to the PL intensity I(B) measured at the same wavelength. This procedure allowed us to correct the shape of the resonance profile by accounting for the PL intensity variations with increasing magnetic field.

III. RESULTS AND DISCUSSION

Photoluminescence three spectra for $CdTe/Cd_{0.86}Mn_{0.14}Te$ QWs are shown in Fig. 1. The emission spectra of all three QWs consist of two strong lines corresponding to excitons (X) localized at well-width fluctuations and to charged exciton complexes, *i.e.* trions (T) consisting of two electrons and one hole [18]. Their formation requires excess of electrons over holes in QWs. Such excess is typical for unintentionally doped CdTe QWs, due to carrier diffusion from the barrier materials with residual n-type doping. The energy difference between the exciton and trion lines varies from 2.5 to 5 meV and increases in narrow wells. It corresponds to the trion binding energy,

which is about an order of magnitude smaller than the binding energy of the quasi-2D excitons.

One can also see in Fig. 1 that the exciton emission line shifts from 1.597 up to 1.678 eV for QW width varied from 30 down to 3.6 nm due to the carrier quantum confinement. We use the energy position of the exciton emission to evaluate the QW width for the studied samples. Model calculations for the exciton PL transition energy and the exciton binding energy have been performed using the procedure described in [19] with the following parameters for our material system: the band gap offset between the well and barrier materials is 223 meV, it is divided in a ratio of 70/30 between the conduction and valence bands; the dielectric constant $\varepsilon = 10$; the in-plane heavy-hole mass was taken as $m_{hh,\parallel}=0.37m_0$; the heavyhole mass along the growth axis, i.e. perpendicular to the QW plane, is $m_{hh,\perp}=0.48m_0$. We have taken into account eight confined electron levels and ten confined hole levels. The results of our calculations are presented in Fig. 2, from which the widths of the quantum wells have been deduced by comparing the experimental exciton PL transition energies with the calculated dependence.

We turn now from the sample characterization to the results of the optically detected resonance. ODR signal could be reliably detected in the QWs with widths $L_Z = 30$, 9 and 3.6 nm. We have found no influence of FIR on the emission from the narrowest QW with $L_Z = 1.2$ nm. Most probably the changes are below the sensitivity level of our setup.

The ODR signal intensity plotted as a function of magnetic field clearly demonstrates a resonance behav-

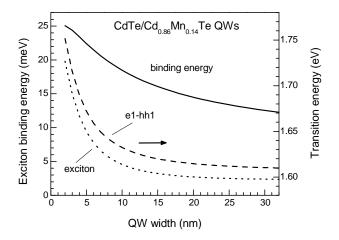


FIG. 2: Exciton energy, exciton binding energy and energy of optical transition between the lowest levels of confined electrons and holes (e1-hh1) calculated for $CdTe/Cd_{0.86}Mn_{0.14}Te$ QWs as function of the QW width.

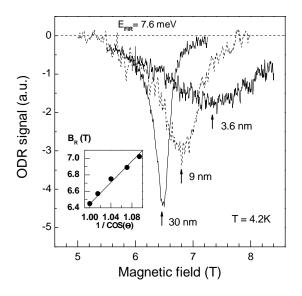


FIG. 3: Magnetic field dependence of ODR signal at $E_{FIR} =$ 7.6 meV measured in CdTe/Cd_{0.86}Mn_{0.14}Te QWs. The shift of the resonance field is given in the insert as function of the tilt angle θ for the 30-nm-wide QW (circles – experiment values; line – fit with 6.45/cos(θ)).

ior (Fig. 3). We have checked that both the resonance field and the shape of the resonance profile are insensitive to the PL detection energy. The ODR signal was recorded at fixed detection energies shown by the arrows in Fig. 1. The ODR signal was normalized to the PL intensity measured at the same detection energy. For all QWs the PL intensity was decreasing by about 30% with increasing magnetic field from 5.5 T to 8 T. This change has very small influence on the shape of the resonance profile and requires correction of the resonance field by less than 0.01 T.

There are three characteristics of the resonance curves to be analyzed: (i) the resonance magnetic field B_R ,

which is directly linked to the value of the electron effective mass; (ii) the resonance full width at the half maximum (FWHM), which is inversely proportional to the electron scattering rate and contains information on the electron mobility, and (iii) the resonance amplitude, which is controlled by the mechanisms responsible for the ODR signal. Before proceeding with discussion of the resonance parameters we shall proof that the observed features originate from the QWs. In order to check the two-dimensional character of electrons responsible for the ODR signal we have carried out the same measurements in tilted magnetic fields. The pronounced shift of the CR resonance toward higher magnetic fields was found to be proportional to 1 / $\cos\theta$ where θ (being varied from 0 ° to 24 $^{\circ}$) is the angle between the magnetic field direction and the structure growth axis. The insert in Fig. 3 illustrates this observation for the 30 nm QW proving that the electrons have quantum confined character.

In the widest QW with 30 nm width, the resonance FWHM is 0.33 T. This corresponds to a momentum relaxation time of 2.4 ps, and to an electron mobility of $3.0 \times 10^4 \text{ cm}^2/(\text{V}\cdot\text{s})$. A decrease of the well width is accompanied by a strong broadening of the resonances up to 0.74 T and 1.9 T for 9 nm and 3.6 nm wells, respectively. The corresponding electron mobilities are 1.4×10^4 and $0.5 \times 10^4 \text{ cm}^2/(\text{V}\cdot\text{s})$. Localization of electrons on QW width fluctuations is known to be the dominating mechanism for resonance broadening in low dimensional structures. Its contribution increases in narrow QWs causing the decrease of the carrier mobility. It goes in line with the increasing width of the photoluminescence emission spectra from 1.7 meV to 3.7 meV for 30 nm and 3.6 nm wells, respectively (see Fig. 1).

The modulation spectra (ODR signal) recorded at the resonance magnetic field are shown in the lower panels of Fig. 1. In the 30 nm QW the FIR radiation results in a decrease of the PL signal by approximately 2.5% for the trion line and a significantly smaller decrease for the exciton line. The ODR signal decreases in narrower QWs, it is about 0.9% for the 9 nm QW and only 0.5% for the 3.6 nm QW. This observation can be attributed to enhanced electron localization and the related decrease of the electron mobility in narrow QWs.

The dominating mechanism of the PL intensity modulation under FIR radiation is related to the specifics of the trion complexes in the studied structures. As one can see in Fig. 1, the strongest ODR signal has been observed in the maximum of the trion emission line and only weak modulations are seen for the exciton line. This is expected since in QWs with a very diluted electron gas the trion emission is much more sensitive to the temperature of the electron gas [18, 20] then the exciton emission. This is due to the fact that for the trion formation one of the electrons is captured from the electron gas and, hence, the probability of the trion formation is very sensitive to the electron resonance conditions decreases the probability for trion formation, which causes a decrease of the trion emission intensity.

Measurement of the resonance magnetic field B_R , where the FIR energy coincides with the cyclotron energy of electrons, allows evaluation of the electron effective mass. Fitting the resonances shown in Fig. 3 by a Lorenzian function we obtained $B_R = 6.45, 6.75$ and 7.25 T for QWs with $L_Z = 30$, 9 and 3.6 nm, respectively. The electron cyclotron mass m_e was evaluated from B_R values using $m_e/m_0 = 0.0152 B_R$ [T], which is derived from $m_e = e\hbar B_R/E_{FIR}$ for $E_{FIR} = 7.6$ meV. We found that m_e increases with decreasing well width: $m_e = 0.099 m_0, \ 0.104 m_0 \text{ and } 0.112 m_0 \text{ for } L_Z = 30, \ 9$ and 3.6 nm. These data are shown by solid circles in Fig. 4. The arrow in the figure marks the electron effective mass of $0.096 m_0$ measured for bulk CdTe [21]. The open circles are experimental data for CdTe/(Cd,Mg)Te QWs with non-magnetic barriers taken from [2]. These results coincide well with our experimental data. For the studied relatively wide QWs the dominating part of the electron wave function is concentrated in the CdTe wells and is not much dependent on the differences in barrier materials. Also, the (Cd,Mn)Te and (Cd,Mg)Te alloys are pretty similar in their properties as these barrier materials provide efficient confinement of both electrons and holes. One may expect that in doped CdTe/(Cd,Mg)Te QWs m_e will be larger due to non-parabolicity of the conduction band at finite k-values given by the Fermi level. However, an estimation of this effect for the electron density of 4×10^{11} cm⁻² gives an m_e increase by 1.2% only [2], which does not exceed the error bar for our experimental data. Comparing the data for the two systems with different barrier materials we can conclude that the electron confinement and the respective increase of the quantum confinement energy is the dominating factor in the m_e dependence on the QW width.

For deeper insight into the electron mass behaviour we have compared the experimental data with results of model calculations. We will follow the commonly used routine in which the bare effective mass m_b is calculated and the polaron correction to the effective mass is fitted with the coupling constant of the electron-phonon interaction α used as a free parameter

$$m_e = m_b \ (1 + \pi \alpha/8). \tag{1}$$

The polaron contribution to the measured carrier effective masses originates from the cloud of optical phonons that "accompany" the electron and make the measured mass "heavier". For example, in bulk CdTe the calculated bare electron effective mass is $0.088 m_0$ and the measured polaron mass is $0.096 m_0$.

A simple analytical approach to calculation of m_b is provided in the frame of 3-band $\mathbf{k} \cdot \mathbf{p}$ technique

$$\frac{m_0}{m_b} = (1+2F) + \frac{E_P \left(E_g + 2\Delta_{SO}/3\right)}{E_g \left(E_g + \Delta_{SO}\right)},$$
 (2)

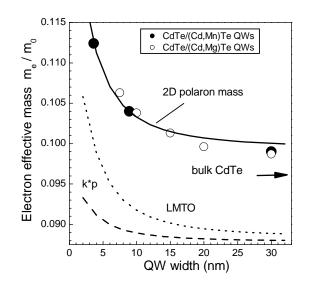


FIG. 4: Electron cyclotron mass versus QW width for CdTe-based quantum wells. Experimental data of this work for CdTe/Cd_{0.86}Mn_{0.14}Te QWs are given by closed circles. Open circles show the data for the modulation-doped CdTe/Cd_{0.88}Mg_{0.12}Te QWs with electron density of 4×10^{11} cm⁻² [2]. The bare electron mass calculated without polaron correction in parabolic-band approximation is shown by the dashed line and that with accounting for conduction band non-parabolicity is given by the dotted line. The solid line shows the calculation after including the electron-phonon interaction with $\alpha = 0.32$.

where $E_P = 21.0 \text{ eV}$ is the interband matrix element, Δ_{so} = 0.93 eV is the spin-orbit splitting, $E_g = 1.59$ eV is the fundamental band gap of CdTe, and F = -0.6 is a parameter accounting for contribution of high energy bands [22, 23, 24]. One can see from Eq.(2) that the effective mass m_b increases for larger band gap values. Exact calculation of m_b in QW structures requires laborious numerical procedures, which include the quantum confinement energy, conduction band non-parabolicity, and penetration of the electron wave function into barriers (see e.g. [25]). However, the 3-band $\mathbf{k} \cdot \mathbf{p}$ approach gives fairly well suited values when E_q in Eq.(2) is replaced by the energy separation between the lowest electron and hole subbands. In Fig. 4 these calculations for CdTe-based QWs in parabolic band approximation are shown by the dashed line. In order to take into account the conduction band non-parabolicity in CdTe, we performed more elaborate calculations based on density functional theory in local density approximation using the linear muffin-tinorbital (LMTO) approach [26]. Calculated dependence for the bare electron mass (the dotted line in Fig. 4) demonstrates the main experimental trend of increasing mass values with narrowing QW width.

Very good agreement with experimental data has been achieved by correcting the bare mass with the polaron effect using Eq.(1). The best fit shown by the solid line has been achieved for $\alpha = 0.32$. This value is in good agreement with the literature data for the electronphonon interaction constant reported for CdTe and CdTe/(Cd,Mn)Te QWs (see [27] and references therein).

To conclude, the optically-detected resonance technique has been used to study electron cyclotron resonance in nominally undoped CdTe/(Cd,Mn)Te QWs. Pronounced modulation of the luminescence intensity has been found for the charged exciton emission, when the residual electrons are resonantly heated by FIR radiation. The evaluated electron effective masses increase with narrowing quantum well width and are in good agreement with data for CdTe QWs confined by (Cd,Mg)Te barriers. Good quantitative agreement with model calculations is

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achieved with an electron-phonon interaction constant α equal to 0.32.

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